Genech Hontony. 8 pp. 7/25/04. Han.

		/ i/		1
L Number	Hits	Search Text	DB	Time stamp
5	0	ep-19731495\$-\$.did.	USPAT;	2004/07/25 19:27
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
6	2	"6051850"	USPAT;	2004/07/25 19:27
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
7	10	"6204717"	USPAT;	2004/07/25 19:27
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			EPO; JPO;	
		· · · · · · · · · · · · · · · · · · ·	DERWENT;	
			IBM_TDB	
8	6	(("6051850") or ("6204717") or	USPAT;	2004/07/25 19:29
		("20030160281")).PN.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
9	2	("6236068").PN.	USPAT;	2004/07/25 19:28
			US-PGPUB;	
Ĩ			EPO; JPO;	
			DERWENT;	
			IBM TDB	
10	7	(("5387528") or ("5702961") or ("6011280")	USPAT	2004/07/25 19:44
		or ("4901127") or ("4636830") or		
		("5973338") or ("5821586")).PN.		
11	3		USPAT;	2004/07/25 20:04
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			EPO; JPO;	
			DERWENT;	
			IBM TDB	
12	2	("20030160281").PN.	USPAT;	2004/07/25 20:04
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
13	49	(US-6172382-\$ or US-5990495-\$ or	USPAT;	2004/07/25 20:49
		US-5418394-\$ or US-5387528-\$ or	US-PGPUB;	
		US-6236068-\$ or US-6204717-\$ or	EPO; JPO;	
		US-5990496-\$ or US-6459108-\$ or	DERWENT	
		US-6184555-\$ or US-6479876-\$ or		
		US-5814548-\$ or US-5413313-\$ or		
		US-6373079-\$ or $US-6274904-$$ or		
1		US-6271562-\$ or US-6046470-\$ or		
ŀ		US-5321281-\$ or US-6011280-\$ or		
		US-6144048-\$ or $US-5252848-$ \$ or		
		US-5479037-\$ or $US-5777362-$$ or		
		US-5821586-\$ or $US-6031265-$ \$ or		
		US-6037631-\$ or $US-4963970-$ \$).did. or		
		(US-6051850-\$ or US-5128730-\$ or		
		US-5073338-\$ or $US-5128730-$ \$ or $US-5973338-$ \$ or		
		US-4636830-\$ or US-6380565-\$).did. or		
		(US-20030122189-\$ or US-20030160281-\$ or		
		US-20020000563-\$ or US-20030025124-\$ or		
		US-20020063280-\$ or US-20020060340-\$).did.		
		or (WO-9931734-\$ or EP-315213-\$ or		
		EP-622853-\$ or EP-503605-\$).did. or		1
l		(JP-06053511-\$ or JP-04234173-\$ or		
		JP-62011275-\$).did. or (JP-09191110-\$ or		
		EP-744834-\$ or CN-1102274-\$ or		1
		EP-622853-\$).did.		1

			_	
14	1	<pre>((US-6172382-\$ or US-5990495-\$ or US-5418394-\$ or US-5387528-\$ or US-6236068-\$ or US-6204717-\$ or US-5990496-\$ or US-6459108-\$ or US-6184555-\$ or US-6479876-\$ or US-5814548-\$ or US-5413313-\$ or US-6373079-\$ or US-6274904-\$ or US-6271562-\$ or US-6046470-\$ or US-6271562-\$ or US-6011280-\$ or US-5321281-\$ or US-6011280-\$ or US-5479037-\$ or US-5252848-\$ or US-5479037-\$ or US-5777362-\$ or US-5479037-\$ or US-5777362-\$ or US-6037631-\$ or US-6031265-\$ or US-6051850-\$ or US-5128730-\$ or US-6051850-\$ or US-5128730-\$ or US-597338-\$ or US-5702961-\$ or US-4636830-\$ or US-6380565-\$).did. or (US-20030122189-\$ or US-20030160281-\$ or US-2002000563-\$ or US-20030025124-\$ or US-2002000563-\$ or US-20020060340-\$).did. or (WO-9931734-\$ or EP-315213-\$ or EP-622853-\$ or EP-503605-\$).did. or (JP-06053511-\$ or JP-04234173-\$ or JP-62011275-\$).did. or (JP-09191110-\$ or EP-744834-\$ or CN-1102274-\$ or EP-622853-\$).did.) and compensation near3 column\$2</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/25 20:45
15	1	<pre>((US-6172382-\$ or US-5990495-\$ or US-5418394-\$ or US-5387528-\$ or US-6236068-\$ or US-6204717-\$ or US-5990496-\$ or US-6459108-\$ or US-6184555-\$ or US-6479876-\$ or US-6184555-\$ or US-6479876-\$ or US-6373079-\$ or US-6274904-\$ or US-6373079-\$ or US-6274904-\$ or US-6271562-\$ or US-6046470-\$ or US-6271562-\$ or US-6011280-\$ or US-6144048-\$ or US-5252848-\$ or US-6144048-\$ or US-5252848-\$ or US-5479037-\$ or US-5777362-\$ or US-6037631-\$ or US-6031265-\$ or US-6051850-\$ or US-5128730-\$ or US-6051850-\$ or US-5128730-\$ or US-5973338-\$ or US-5702961-\$ or US-4636830-\$ or US-6380565-\$).did. or (US-2002000563-\$ or US-20030025124-\$ or US-2002000563-\$ or US-20030055-\$ or US-62853-\$ or EP-503605-\$ or US-62853-\$ or EP-503605-\$ or US-62853-\$ or US-62853-\$ or CN-1102274-\$ or EP-622853-\$ or CN-1102274-\$ or EP-622853-\$ or CN-1102274-\$ or</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/25 20:45
16	256	regions (257/133).CCLS.	USPAT; US-PGPUB	2004/07/25 20:49
17	60	(257/134).CCLS.	USPAT; US-PGPUB	2004/07/25 20:49
18	92	(257/135).CCLS.	USPAT; US-PGPUB	2004/07/25 20:49
19	558	(257/328).CCLS.	USPAT; US-PGPUB	2004/07/25 20:49
20	458	(257/329).CCLS.	USPAT; US-PGPUB	2004/07/25 20:49
21	759	(257/330).CCLS.	USPAT; US-PGPUB	2004/07/25 20:50
22	683	(257/341).CCLS.	USPAT; US-PGPUB	2004/07/25 20:50
23	282	(257/342).CCLS.	USPAT; US-PGPUB	2004/07/25 20:50
24	282	(257/342).CCLS.	USPAT; US-PGPUB	2004/07/25 20:50
25	235	(257/354).CCLS.	USPAT; US-PGPUB	2004/07/25 20:50

26	1011	(257/355).CCLS.	USPAT;	2004/07/25 20:50
20	1 1011		US-PGPUB	2004/07/23 20.30
27	3484	((257/133).CCLS.) ((257/134).CCLS.) ((257/135).CCLS.) ((257/328).CCLS.) ((257/329).CCLS.) ((257/330).CCLS.)	USPAT; US-PGPUB	2004/07/25 20:51
		((257/341).CCLS.) ((257/342).CCLS.) ((257/342).CCLS.) ((257/354).CCLS.) ((257/355).CCLS.)		
28	3	<pre>(((257/133).CCLS.) ((257/134).CCLS.) ((257/135).CCLS.) ((257/328).CCLS.) ((257/329).CCLS.) ((257/330).CCLS.) ((257/341).CCLS.) ((257/342).CCLS.) ((257/342).CCLS.) ((257/354).CCLS.) ((257/355).CCLS.)) and punch-through and</pre>	USPAT; US-PGPUB	2004/07/25 20:53
		compensation and power near2 (semiconductor transistor).ti,ab,clm. and avalanche		
29	11	(((257/133).CCLS.) ((257/134).CCLS.) ((257/135).CCLS.) ((257/328).CCLS.) ((257/329).CCLS.) ((257/330).CCLS.) ((257/341).CCLS.) ((257/342).CCLS.) ((257/342).CCLS.) ((257/354).CCLS.) ((257/355).CCLS.)) and punch-through and power near2 (semiconductor	USPAT; US-PGPUB	2004/07/25 20:54
		<pre>transistor).ti,ab,clm. and avalanche and (break\$down withstand)</pre>		
30	52	US-4963970-\$ or US-5128730-\$ or US-5973338-\$ or US-6380565-\$ or US-6144048-\$ or US-5321281-\$ or US-6046470-\$ or US-6011280-\$ or US-6037631-\$ or US-6031265-\$ or	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/07/25 20:54
		US-5821586-\$ or US-5777362-\$ or US-5479037-\$ or US-5252848-\$ or US-5990495-\$ or US-6172382-\$ or US-5990496-\$ or US-6184555-\$ or US-6479876-\$ or US-6184555-\$ or US-5413313-\$ or US-6373079-\$ or US-5418394-\$ or US-6459108-\$).did. or (US-6051850-\$ or US-4636830-\$ or US-5702961-\$ or US-4636830-\$ or US-6410950-\$ or US-6498368-\$ or US-6410950-\$ or US-654560-\$ or US-5387528-\$ or US-6236068-\$ or US-20020060340-\$ or US-2002000563-\$ or US-20030122189-\$ or US-20030025124-\$ or US-20030160281-\$).did. or (EP-503605-\$ or		
		EP-622853-\$ or EP-315213-\$ or WO-9931734-\$).did. or (JP-04234173-\$ or JP-62011275-\$ or JP-06053511-\$).did. or (EP-622853-\$ or CN-1102274-\$ or EP-744834-\$ or JP-09191110-\$).did.		
-	3		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/09/22 17:05
-	34	257/\$6.ccls. and power.ti,ab. and igfet.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/05/28 21:31
-	1	257/\$6.ccls. and power.ti,ab. and (vertical adj igfet or v-igfet).ti,ab.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/28 21:32
-	20	okabe.in. and igbt.ti,ab.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/28 21:43
Search His	tory 7/	25/04 9:18:33 PM Page 3		

-	23	vertical adj igfet.ti,ab.	USPAT;	2002/05/29 10:22
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	0	(acution accu2 benuice odi loven) accu12	IBM_TDB USPAT;	2002/05/29 11:42
-	0	(portion near3 barrier adj layer) near12		2002/05/29 11:42
		lattice adj match\$3	US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	3	("5484740").PN.	USPAT;	2002/05/29 12:36
-	J 3	(J464/40).EN.	US-PGPUB;	2002/03/29 12.30
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	0	("method.clm. and (source adj contact or	USPAT;	2002/05/29 12:38
		drain adj contact).clm. and gate.clm. and	US-PGPUB;	
		after.clm. or nefore.clm.").PN.	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	119		USPAT;	2002/05/29 12:39
		drain adj contact).clm. and gate.clm. and	US-PGPUB;	
		after.clm. or nefore.clm.	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	13		USPAT;	2002/05/29 13:52
		drain adj contact).clm. same gate.clm.	US-PGPUB;	
		same (after or before).clm.	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	3	("5484740").PN.	USPAT;	2002/05/29 15:17
			US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
	2	("6144048").PN.	USPAT;	2002/05/29 15:17
	۷ ۲	(0144040).rN.	US-PGPUB;	2002/03/23 13.17
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	3	("5789760").PN.	USPAT;	2002/05/29 15:18
	_		US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	0	"64-81270"	JPO	2002/05/29 16:57
-	0	"6481270"	JPO	2002/05/29 16:57
-	0	"36481270"	JPO ·	2002/05/29 16:57
-	0	"036481270"	JPO	2002/05/29 16:57
-	0	"03-6481270"	JPO	2002/05/29 16:57
-	0	"0364-81270"	JPO	2002/05/29 16:57
-	0	"64-81270"	JPO	2002/05/29 17:00
-	0	jp-6481270\$-\$.did.	JPO	2002/05/29 17:00
_	0	jp-36481270\$-\$.did.	JPO	
_	0	jp-036481270\$-\$.did. jp-81270\$-\$.did.	JPO	2002/05/29 17:01
_	520	jp-812705-5.d1d. igfet	JPO	2002/05/29 17:01
-	11	igfet and okabe.in.	JPO JPO	2002/05/29 17:01 2002/05/29 17:05
-	2	igfet and voltage adj diode	JPO	2002/05/29 17:05
-	0	5973338.pn.	JPO	2002/05/29 17:25
_	1	5973338.pn.	USPAT;	2002/05/29 17:23
		· · · · · · · · · · · · · · · · · · ·	US-PGPUB	
-	1	"5399883".PN.	USPAT	2002/05/29 17:26
-	1	"5095343".PN.	USPAT	2002/05/29 17:27
-	1	"4994871".PN.	USPAT	2002/05/29 17:27
-	1	"4994871".PN.	USPAT	2002/05/29 17:27
-	1	"4985743".PN.	USPAT	2002/05/29 17:27
-	81	(257/135).CCLS.	USPAT;	2002/05/29 17:54
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
Search His	toru 7/	25/04 9:18:33 PM Page 4		

-	3	("5702961").PN.	USPAT; US-PGPUB;	2002/05/29 19:35
			EPO; JPO;	
			DERWENT;	
	81	(257/135).CCLS.	IBM_TDB USPAT;	2002/05/29 19:35
-	01		US-PGPUB;	2002/05/29 19:55
			EPO; JPO;	
			DERWENT;	
	0	("L28 and punch-through adj (region or	IBM_TDB USPAT;	2002/05/29 19:36
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			DERWENT;	
_	0	((257/135).CCLS.) and punch-through adj	IBM_TDB USPAT;	2002/05/29 19:36
	, i	(region or layer)	US-PGPUB;	
	l		EPO; JPO;	
			DERWENT; IBM TDB	
-	62	punch-through adj region	USPAT;	2002/05/29 20:08
			US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
-	0	ep-0061551\$-\$.did.	USPAT;	2002/05/29 20:09
		-	US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
-	0	ep-061551\$-\$.did.	USPAT;	2002/05/29 20:13
			US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
-	0	ep-0503605\$-\$.did.	USPAT;	2002/05/29 20:13
			US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM_TDB	
-	1	"503605"	EPO	2002/05/29 20:16
-	U	(igbt or v-igbt or igfet or v-igfet or vertical adj bipolar adj transistor or	EPO	2002/05/29 20:18
		vertical adj insulated adj gate).ti,ab.		
	10	and edge adj termin\$5		
-	19	(igbt or v-igbt or igfet or v-igfet or vertical adj bipolar adj transistor or	USPAT; US-PGPUB;	2002/05/29 20:24
		vertical adj insulated adj gate).ti,ab.	EPO; JPO;	
		and edge adj termin\$5	DERWENT;	
	169	edge adj termination and (257/\$6.ccls. or	IBM TDB	2002/05/20 20-25
	109	438/\$6.ccls.)	USPAT; US-PGPUB;	2002/05/29 20:25
			EPO; JPO;	
			DERWENT;	
_	4	edge adj termination and igbt.ti,ab. and	IBM_TDB USPAT;	2002/05/29 20:36
		(257/\$6.ccls. or 438/\$6.ccls.)	US-PGPUB;	2002/03/23 20:30
			EPO; JPO;	
			DERWENT;	
-	0	(magneto adj resist\$4 or magneto-resist\$3)	IBM_TDB USPAT;	2002/05/29 20:45
		and igbt.ti,ab. and (257/\$6.ccls. or	US-PGPUB;	
		438/\$6.ccls.)	EPO; JPO; DEDMENT.	
			DERWENT; IBM TDB	
-	11	(channel adj stop\$3) and igbt.ti,ab. and	USPAT;	2002/05/29 21:17
		(257/\$6.ccls. or 438/\$6.ccls.)	US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
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	<u> </u>			
-	81	(257/135).CCLS.	USPAT;	2002/05/29 21:17
			US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	34	(punch adj through or punch-through or	USPAT;	2002/05/30 10:26
		punchthrough) and vertical.ti,ab. and	US-PGPUB;	
		(igfet or ight or v-ight or v-igfet)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	1698	((257/339) or (257/354) or	USPAT;	2002/05/30 10:53
		(257/355)).CCLS.	US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
-	105	(((257/339) or (257/354) or	USPAT;	2002/05/30 13:57
	105	(257/355)).CCLS.) and (vertical or v-igbt	US-PGPUB;	2002/03/30 13.07
		ot v-igfet).ti,ab.	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	486	(257/328).CCLS.	USPAT;	2002/05/30 14:18
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
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-	2	(J30/J20).EN.	US-PGPUB;	2002/03/30 14.23
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	3	("5702961").PN.	USPAT;	2002/05/30 14:23
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		(#6011000#) - 53	IBM_TDB	
-	2	("6011280").PN.	USPAT;	2002/05/30 14:24
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			DERWENT;	
			IBM TDB	
-	2	("4901127").PN.	USPAT;	2002/05/30 14:25
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	2	(#4626020#) - 53	IBM_TDB	0000/05/00 14 05
-	3	("4636830").PN.	USPAT; US-PGPUB;	2002/05/30 14:25
		•	EPO; JPO;	
	1		DERWENT;	
			IBM TDB	
-	2	("5973338").PN.	USPAT;	2002/05/30 14:26
1			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	3	("5921596") DN	IBM_TDB	2002/05/20 14-00
-		("5821586").PN.	USPAT; US-PGPUB;	2002/05/30 14:26
			EPO; JPO;	
			DERWENT;	
]		IBM TDB	
-	2342	((257/135) or (257/328) or (257/339) or	USPAT;	2002/09/22 15:48
		(257/354) or (257/355)).CCLS.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
_	17	1/1257/135) or 1257/2201 or 1257/2201	IBM_TDB	2002/00/22 15.50
-	L 1	(((257/135) or (257/328) or (257/339) or (257/354) or (257/355)).CCLS.) and second	USPAT; US-PGPUB;	2002/09/22 15:50
		adj electrode and vertical.ti,ab.	EPO; JPO;	
		and reference and reference, and	DERWENT;	
			IBM TDB	
·				<u> </u>

-	0	(((257/135) or (257/328) or (257/339) or (257/354) or (257/355)).CCLS.) and compensator and vertical.ti,ab.	USPAT; US-PGPUB; EPO; JPO;	2002/09/22 15:51
			DERWENT; IBM TDB	
-	0	(((257/135) or (257/328) or (257/339) or (257/354) or (257/355)).CCLS.) and compensator and vertical	USPĀT; US-PGPUB; EPO; JPO; DERWENT;	2002/09/22 15:51
-	2	("5042043").PN	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/09/23 15:13
-	107	(257/79.ccls. or 257/8\$5.ccls. or 257/9\$5.ccls. or 257/100.ccls. or 257/101.ccls. or 257/102.ccls. or 257/103.ccls.) and (buffer adj layer same	IBM_TDB USPAT; US-PGPUB	2002/09/23 15:17
	73	(amorphous or single adj crystal or crystalline or single-crystal)) and (led or light-emitting or light adj emitting).ti,ab.	110.23.00.	2002/00/22 15:10
	/3	(257/79.ccls. or 257/8\$5.ccls. or 257/9\$5.ccls. or 257/100.ccls. or 257/101.ccls. or 257/102.ccls. or 257/103.ccls.) and (buffer adj layer near10 (amorphous or single adj crystal or crystalline or single-crystal)) and (led or light-emitting or light adj emitting).ti,ab.	USPAT; US-PGPUB	2002/09/23 15:18
-	61	(257/79.ccls. or 257/8\$5.ccls. or 257/9\$5.ccls. or 257/100.ccls. or 257/101.ccls. or 257/102.ccls. or 257/103.ccls.) and (buffer adj layer near5 (amorphous or single adj crystal or crystalline or single-crystal)) and (led or light-emitting or light adj emitting).ti,ab.	USPAT; US-PGPUB	2002/09/23 15:18
-	16	depletion adj zone near12 (extend or extends or extending or reach or reaches or reaching) and (vertical or vmos or umos or vmosfet or umsofet).ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/02/08 14:17
	15	<pre>(space adj charge or space-charge) adj zone near12 (extend or extends or extending or reach or reaches or reaching) and (vertical or vmos or umos or vmosfet or umsofet).ti,ab,clm.</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/02/08 14:19
-	15	<pre>(space adj charge or space-charge) adj zone near12 (extend or extends or extending or reach or reaches or reaching) and (vertical or vmos or umos or vmosfet or umosfet).ti,ab,clm.</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/02/08 14:42
-	28	(space adj charge or depletion or space-charge) adj zone near12 (extend or extends or extending or reach or reaches or reaching) and (vertical or vmos or umos or vmosfet or umosfet).ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/02/08 17:57
-	16		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/02/08 17:58
-	2	(magneto-resistor or magnetoresistor) near6 source and power near3 semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/02/08 18:05

1			· · · · · · · · · · · · · · · · · · ·	
-	2	(magneto-resistor or magnetoresistor)	USPAT;	2003/02/08 18:05
		near6 source and power near3 (mos or	US-PGPUB;	
		mosfet or semiconductor)	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	16	(magneto-resistor or magnetoresistor)	USPAT;	2003/02/08 18:05
		near6 source and (mos or mosfet or	US-PGPUB;	
		semiconductor)	EPO; JPO;	
		Semiconductor,	DERWENT;	
	1		IBM TDB	
	5		USPAT;	2003/02/08 18:14
-	5			2003/02/08 18:14
		near6 source and (mos or mosfet or	US-PGPUB;	
		<pre>semiconductor).ti,ab.clm.</pre>	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	53	deboy.in. and semiconductor.ti,ab.	USPAT;	2003/02/08 18:15
1			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	1
			IBM TDB	
-	0	("jp-4234173\$-\$.did.").PN.	USPAT;	2003/07/21 17:22
	l	()p 12011/00 0.010. /.IN.	US-PGPUB;	2003/07/21 17:22
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	2	jp-04234173\$-\$.did.	USPAT;	2003/07/21 17:31
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	2643	((257/135) or (257/328) or (257/339) or	USPAT;	2003/07/21 17:31
		(257/354) or (257/355)).CCLS.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	213	(((257/135) or (257/328) or (257/339) or	USPAT;	2003/07/21 17:32
		(257/354) or $(257/355)$.CCLS.) and	US-PGPUB;	
]		(punch-through or breakdown or	EPO; JPO;	
		punchthrough) and vertical.ti,ab,clm.	DERWENT;	
		paneneniougn, una vercicar.cr/ab/cim.	IBM TDB	
	0	("jp-10-163526\$-\$.did.").PN.	USPAT;	2003/07/21 18:37
		()p-10-1000209-9.010.).EN.	1 .	2003/07/21 18:37
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	2	jp-10163526\$-\$.did.	USPAT;	2003/07/21 18:37
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	· ·
			IBM TDB	1